

# NX6314EH

LASER DIODE

1 310 nm InGaAsP MQW-DFB LASER DIODE

FOR 1.25 Gb/s FTTH P2P AND 3 Gb/s BTS

R08DS0054EJ0100

Rev.1.00

Jan 19, 2012

## DESCRIPTION

The NX6314EH is a 1 310 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD.

## APPLICATIONS

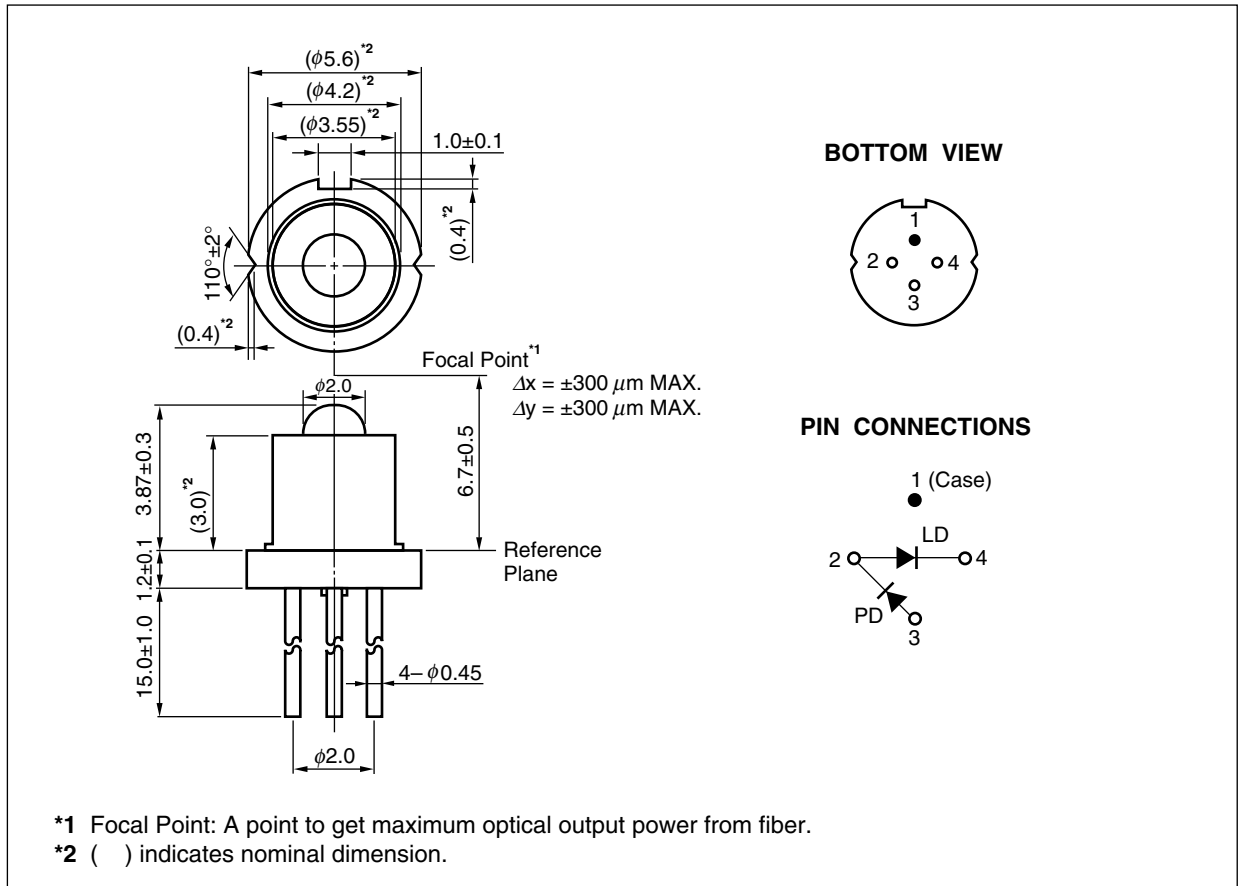
- 1.25 Gb/s FTTH P2P
- 3 Gb/s BTS

## FEATURES

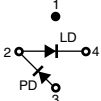
- |                                    |   |
|------------------------------------|---|
| • Optical output power             | $P_O = 5.0 \text{ mW}$                    |
| • Low threshold current            | $I_{th} = 10 \text{ mA}$                  |
| • Differential efficiency          | $\eta_d = 0.4 \text{ W/A}$                |
| • Wide operating temperature range | $T_C = -40 \text{ to } +85^\circ\text{C}$ |
| • InGaAs monitor PIN-PD            |   |
| • CAN package                      | $\phi 5.6 \text{ mm}$                     |
| • Focal point                      | 6.7 mm                                    |



PACKAGE DIMENSIONS (UNIT: mm)



## ORDERING INFORMATION

Part Number	Package	Pin Connections
NX6314EH	4-pin CAN with ball lens cap	

- Remarks**
1. The color of ball lens cap might be observed differently.
  2. The hermetic test will be performed as AQL 1.0%.

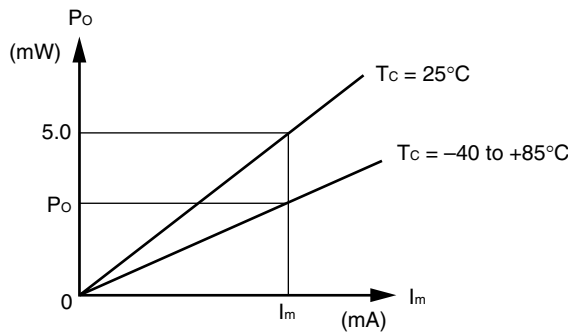
**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C, unless otherwise specified)**

Parameter	Symbol	Ratings	Unit
Optical Output Power	P <sub>O</sub>	20	mW
Forward Current of LD	I <sub>F</sub>	150	mA
Reverse Voltage of LD	V <sub>R</sub>	2.0	V
Forward Current of PD	I <sub>F</sub>	10.0	mA
Reverse Voltage of PD	V <sub>R</sub>	15	V
Operating Case Temperature	T <sub>C</sub>	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	-40 to +85	°C
Lead Soldering Temperature	T <sub>sld</sub>	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

**ELECTRICAL/OPTICAL CHARACTERISTICS  
(T<sub>C</sub> = 25°C, CW, BOL, unless otherwise specified)**

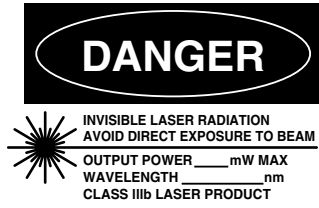
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating Voltage	V <sub>op</sub>	P <sub>O</sub> = 5.0 mW, T <sub>C</sub> = -40 to 85°C	-	1.1	1.6	V
Threshold Current	I <sub>th</sub>		-	10	20	mA
		T <sub>C</sub> = -40 to 85°C	-	30	50	
Differential Efficiency	η <sub>d</sub>	P <sub>O</sub> = 5.0 mW	0.3	0.4	-	W/A
		P <sub>O</sub> = 5.0 mW, T <sub>C</sub> = -40 to 85°C	0.14	-	-	W/A
Peak Emission Wavelength	λ <sub>p</sub>	P <sub>O</sub> = 5.0 mW, T <sub>C</sub> = -40 to 85°C	1 290	-	1 330	nm
Side Mode Suppression Ratio	SMSR	I <sub>F</sub> = I <sub>th</sub> + 20 mA, T <sub>C</sub> = -40 to 85°C	30	-	-	dB
Rise Time	t <sub>r</sub>	I <sub>b</sub> = I <sub>th</sub> , 20-80% P <sub>O</sub> = 5.0 mW	-	100	150	ps
Fall Time	t <sub>f</sub>	I <sub>b</sub> = I <sub>th</sub> , 80-20% P <sub>O</sub> = 5.0 mW	-	100	150	ps
Monitor Current	I <sub>m</sub>	V <sub>R</sub> = 1.5 V, I <sub>F</sub> = I <sub>th</sub> + 20 mA, T <sub>C</sub> = 25°C	80	250	1 000	μA
Monitor Dark Current	I <sub>D</sub>	V <sub>R</sub> = 5 V	-	-	100	nA
Tracking Error **1	γ	I <sub>m</sub> = const. (@ P <sub>O</sub> = 5.0 mW, T <sub>C</sub> = 25°C)	-1.0	-	1.0	dB

Note: 1. Tracking Error: γ

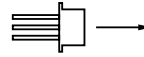


$$\gamma = \left| 10 \log \frac{P_O}{5.0} \right| \text{ [dB]}$$

**SAFETY INFORMATION ON THIS PRODUCT**



**SEMICONDUCTOR LASER**



**AVOID EXPOSURE-Invisible**  
Laser Radiation is emitted from  
this aperture

<p><b>Warning</b> Laser Beam</p>	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> <li>• Do not look directly into the laser beam.</li> <li>• Avoid exposure to the laser beam, any reflected or collimated beam.</li> </ul>
<p><b>Caution</b> GaAs Products</p>	<p>This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.</p> <ul style="list-style-type: none"> <li>• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.             <ol style="list-style-type: none"> <li>1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> <li>2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li> </ol> </li> <li>• Do not burn, destroy, cut, crush, or chemically dissolve the product.</li> <li>• Do not lick the product or in any way allow it to enter the mouth.</li> </ul>

<b>Revision History</b>	<b>NX6314EH Data Sheet</b>
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<b>Rev.</b>	<b>Date</b>	<b>Description</b>	
		<b>Page</b>	<b>Summary</b>
1.00	Jan 19, 2012	–	First edition issued

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